NSN 5961-01-013-9350

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AeroBase Group

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Inclosure Material:

Metal

Overall Length:

0.830 inches

Overall Height:

Between 0.250 inches and 0.300 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

80.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open and 80.0 collector to base voltage/static/emitter open

Current Rating Per Characteristic:

8.00 amperes source cutoff current and 120.00 milliamperes source cutoff current

Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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